

HALOGEN

FREE

AUTOMOTIVE GRADE Available



Vishay General Semiconductor

High Current Density Surface Mount Schottky Barrier Rectifier



DO-220AA (SMP)

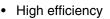
PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V _{RRM}	50 V, 60 V				
I _{FSM}	50 A				
E _{AS}	11.25 mJ				
V _F at I _F = 1.0 A	0.43 V				
T _J max.	150 °C				

TYPICAL APPLICATIONS

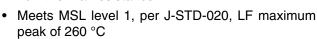
For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses



· Low thermal resistance



- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishav.com/applications

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating.

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS1P5L	SS1P6L	UNIT		
Device marking code		15L	16L			
Maximum repetitive peak reverse voltage	V _{RRM}	50 60		V		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	1.0		Α		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50		А		
Non-repetitive avalanche energy at $I_{AS} = 1.5 \text{ A}$, $T_A = 25 ^{\circ}\text{C}$	E _{AS}	11.25		mJ		
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150		°C		

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SS1P5L & SS1P6L

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage (1)	I _F = 1.0 A I _F = 1.0 A	T _A = 25 °C T _A = 125 °C	V _F	0.52 0.43	0.59 0.52	V	
Reverse current (2)	rated V _R	T _A = 25 °C T _A = 125 °C	I _R	1.6	100 10	μA mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	80	-	pF	

Notes:

 $^{^{(2)}}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	SS1P5L	SS1P6L	UNIT	
Typical thermal resistance ⁽¹⁾	$R_{ hetaJA} \ R_{ hetaJL}$	125 25		°C/W	

Note:

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 mm x 5.0 mm copper pad areas. R_{BJL} is measured at the terminal of cathode band.

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS1P6L-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
SS1P6L-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
SS1P6LHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
SS1P6LHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note:

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

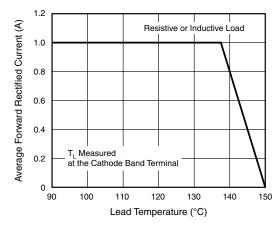


Figure 1. Maximum Forward Current Derating Curve

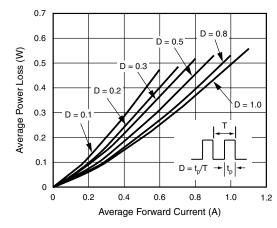


Figure 2. Forward Power Loss Characteristics

 $^{^{(1)}}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

⁽¹⁾ Automotive grade

SS1P5L & SS1P6L



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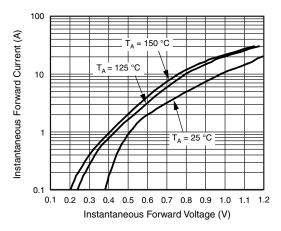


Figure 3. Typical Instantaneous Forward Characteristics

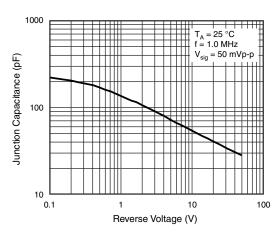


Figure 5. Typical Junction Capacitance

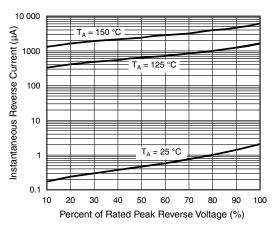


Figure 4. Typical Reverse Leakage Characteristics

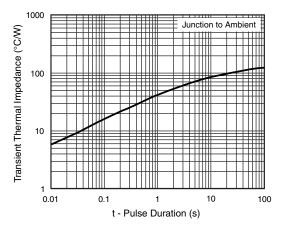
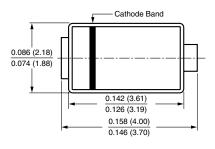
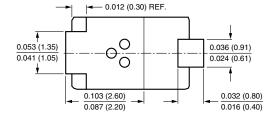


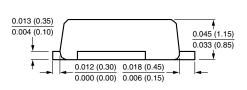
Figure 6. Typical Transient Thermal Impedance

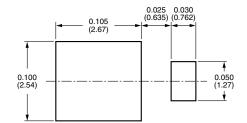
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)









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